Docket No.

<u>Page</u>

GEN0009-US

Declaration For Patent Application

English Language Declaration

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

METHOD FOR MANUFACTURING GATE STRUCTURE FOR USE IN SEMICONDUCTOR DEVICE

the specification of wh	ich		
(check one)			
☑ is attached hereto☑ was as filed on		as United States Application No	o. or PCT International
Application Numb			
and was amende	d on	(if applicable)	
I hereby state that I hincluding the claims,	nave reviewed and under as amended by any state	rstand the contents of the above identi ement referred to above.	fied specification,
Section 1.56.	material to pateritability	ited States Patent and Trademark Off as defined in Title 37, Code of Fed	
Section 365(b) of an PCT International a	y foreign application(s) to pplication which designa re also identified below, loor PCT International a	er Title 35, United States Code, Secondary patent or inventor's certificate, or Secondary at least one country other than by checking the box, any foreign application having a filing date that of	the United States,
Prior Foreign Applic	ant(s)		Priority Not Claimed
Phon to ordigit Applie	۵(-)		
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
			ffice-U.S. DEPARTMENT OF COMME
	Р	02/REV02 Patent and Trademark C	MILCE-U.S. DEI ARTIMETTI GI

(Application Serial No.)	(Filing Date)	
(Application Serial No.)	(Filing Date)	
(Application Serial No.)	(Filing Date)	_
ection 365(c) of any PCT Interna sofar as the subject matter of e nited States, or PCT Internations	itional application designating ach of the claims of this appl al application in the manner pr	ny United States application(s), or the United States, listed below and, ication is not disclosed in the prior rovided by the first paragraph of 35
ection 365(c) of any PCT Internation as the subject matter of expired States, or PCT Internationals. S.C. Section 112, I acknowledge ffice all information known to mection 1.56 which became avaitional or PCT International filing	ational application designating ach of the claims of this application in the manner pretent the duty to disclose to the U e to be material to patentabiliable between the filing date date of this application.	the United States, listed below and, ication is not disclosed in the prior
ection 365(c) of any PCT Internal sofar as the subject matter of e nited States, or PCT International S.C. Section 112, I acknowledge ffice all information known to mection 1.56 which became ava	itional application designating ach of the claims of this appled application in the manner presented to the U eto be material to patentabiliable between the filing date	the United States, listed below and, ication is not disclosed in the prior rovided by the first paragraph of 35 nited States Patent and Trademark ity as defined in Title 37, C. F. R., e of the prior application and the
ection 365(c) of any PCT Internation as the subject matter of expired States, or PCT Internationals. S.C. Section 112, I acknowledge ffice all information known to mection 1.56 which became avaitional or PCT International filing	ational application designating ach of the claims of this application in the manner pretent the duty to disclose to the U e to be material to patentabiliable between the filing date date of this application.	the United States, listed below and, ication is not disclosed in the prior rovided by the first paragraph of 35 nited States Patent and Trademark ity as defined in Title 37, C. F. R., e of the prior application and the

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. (list name and registration number)

Michael D. Bednarek, Reg. No. 32,329

Lawrence J. Gotts, Reg. No. 31,163

Aslan Baghdadi, Reg. No. 34,542

Elizabeth M. Roesel, Reg. No. 34,878

David C. Isaacson, Reg. No. 38,500

Michael S. Lee, Reg. No. 41,434

Steven P. Arnheim, Reg. No. 43,475

Poh C. Chua, Reg. No. 44,615

Michael A. Oblon, Reg. No. 42,956

Lawrence D. Eisen, Reg. No. 41,009

James M. Ross, Reg. No. 42,115 Michelle Marks, Reg. No. 41,971 Michael Colby, Reg. No. 45,816 32,329

Joanne Kim, Reg. No. 51,193

Send Correspondence to:

Michael D. Bednarek

Shaw Pittman LLP

1650 Tysons Boulevard

McLean, VA 22102

NO.3, LANE 76, CILIDAN RD., JIAOSI TOWNSHIP, YILAN COUNTY 262, TAIWAN, R.O.C.

Direct Telephone Calls to:

(name and telephone number)

Michael D. Bednarek at 703/770-7606

Full name of sole or first inventor		
TZU-EN HO		
Sole of first inventor's signature	Date	11/21/200}
Tzu-En 40.	Date	11/21/2003
Residence		
NO.3, LANE 76, CILIDAN RD., JIAOSI TOWNSHIP, YILAN COUNTY 262, TAIWAN, R.O.C.		
Citizenship		
TAIWAN, R.O.C.		
Post Office Address		

Full name of second inventor, if any

CHANG-RONG WU

Second inventor's signature

Chang-Rong Wu

Residence

26F, NO.28-9, SEC. 1, MINSHENG RD., BANCIAO CITY, TAIPEI COUNTY 220, TAIWAN, R.O.C.

Citizenship

TAIWAN, R.O.C.

Post Office Address

26F, NO.28-9, SEC. 1, MINSHENG RD., BANCIAO CITY, TAIPEI COUNTY 220, TAIWAN, R.O.C.

Full name of third inventor, if any	
VI NANI CHENI	
H-NAN CHEN	
Second inventor's signature	Date 15 7
	Date Nov. of you?
) - Phen	(001. ///
Residence	
NO.4, LANE 151, JIANMIN RD., TAIPEI CITY 112, TAIWAN, R.O.C.	
Citizenship	
TAIWAN, R.O.C.	
Post Office Address	
NO.4, LANE 151, JIANMIN RD., TAIPEI CITY 112, TAIWAN, R.O.C.	

Full name of fourth inventor, if any	
KUO-CHIEN WU	
Second inventor's signature	Date Alay at 1 and
KUO-CHIEN WU	Date Nov. 21, 2003
Residence	
NO.547, JHONGJHENG RD., MIAOLI CITY, MIAOLI COUNTY 360, TAIWAN	
Citizenship	
TAIWAN, R.O.C.	
Post Office Address	
NO.547, JHONGJHENG RD., MIAOLI CITY, MIAOLI COUNTY 360, TAIWAN	
	•